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U.S. PATENT DOCUMENTS					
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5,889,686	3/30/99	Mimotogi et al.			
					
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FOREIGN PATENT DOCUMENTS						
	Document Number	Publication Date	Country	Class	Sub Class	Translation Yes or No
	2000-29217	1/28/00	Japan			Abstract
	4-44312	2/14/92	Japan			Abstract
	1-188859	7/28/89	Japan			Abstract

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)
Nakamura et al., "Influence of Alkaline Concentration Variation on CD in KrF Resist Development," Journal of Photopolymer Science and Technology (4/20/01), pp. 435-438
Nakamura et al., "Impact of Development Reaction Products on CD in View of Developer Alkaline Concentration Deviation," SPIE (2001), p. 729

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